L Number	Hits	Search Text	DB	Time stamp
1	2	6108191.pn.	USPAT;	2001/08/20
			US-PGPUB;	17:18
			EPO; JPO; DERWENT;	
			IBM TDB	
2	1	US-6108191-A.DID.	DERWENT	2001/08/20
		2010507	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	16:38
3	3	3210607.pn.	USPAT; US-PGPUB;	2001/08/20
			EPO; JPO;	
			DERWENT;	
	18	two adj different adj dielectric and	IBM TDB USPAT;	2001/08/16
_	10	capacitor and (257/\$ 438/\$)	US-PGPUB;	17:38
			EPO; JPO;	
]			DERWENT;	
_	8	("3210607"   "4219866"   "5036424"	IBM TDB   USPAT	2001/08/16
		"5036425"   "5117326"   "5561587"		17:20
		"5668694"   "5905049").PN.		
-	0	6108191.URPN.	USPAT	2001/08/16
_	0	6108191.URPN.	USPAT	2001/08/16
		01001321011111		17:21
-	2	6136725.pn.	USPAT;	2001/08/16
			US-PGPUB; EPO; JPO;	17:22
			DERWENT;	,
			IBM TDB	
-	0	6136725.URPN.	USPAT	2001/08/16
_	1	US-6136725-A.DID.	DERWENT	2001/08/16
	_			17:22
-	2	6108191.pn.	USPAT;	2001/08/16
			US-PGPUB; EPO; JPO;	17.24
			DERWENT;	
		C100101 WDDV	IBM TDB	2001/09/16
-	0	6108191.URPN.	USPAT	2001/08/16 17:23
_	1	US-6108191-A.DID.	DERWENT	2001/08/16
	_			17:23
-	1	de-4300808-\$.did.	USPAT; US-PGPUB;	2001/08/16 17:25
			EPO; JPO;	1,120
			DERWENT;	
	7	ep-298811-\$.did. ep-617440-\$.did.	IBM TDB USPAT;	2001/08/16
_	<b>'</b>	ep-238811-3.did. ep-01/440 5.did. ep-664548-\$.did. de-3442790-\$.did.	US-PGPUB;	17:28
		de-4300808-\$.did.	EPO; JPO;	
			DERWENT;	
_	259	(different combination) adj dielectric	USPAT;	2001/08/16
		and capacitor and (257/\$ 438/\$)	US-PGPUB;	20:19
			EPO; JPO;	
			DERWENT;	
-	66		USPAT;	2001/08/16
		and capacitor and (257/\$ 438/\$)) and	US-PGPUB;	20:21
		(tantalum adj oxide "Ta.sub.20.sub.5" "Ta.sub.2 O.sub.5" tantalum adj	EPO; JPO; DERWENT;	
		pentoxide)	IBM TDB	
-	188	different adj dielectric and capacitor	USPAT;	2001/08/16
		and (257/\$ 438/\$)	US-PGPUB; EPO; JPO;	20:20
			DERWENT;	
			IBM TDB	

_	51	(different adj dielectric and capacitor and (257/\$ 438/\$)) and (tantalum adj oxide "Ta.sub.20.sub.5" "Ta.sub.2 O.sub.5" tantalum adj pentoxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2001/08/17 00:02
_	51	crystalline adj structure with (silicon adj nitride "Si.sub.3N.sub.4" "Si.sub.3N.sub.4" "Si.sub.3N.sub.4" SiN)	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2001/08/16 22:48
_	3393	nitride silicon adj oxide titanium adj oxide titanium adj dioxide alumina aluminum adj oxide "Si.sub.3.N.sub.4" "Si.sub.3 N.sub.4" "SiO.sub.2" "Si O.sub.2" "TiO.sub.2" "Ti O.sub.2"	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 23:58
-	462	"Al.sub.20.sub.3" "Al.sub.2 O.sub.3") (amorphous adj (dielectric silicon adj nitride silicon adj oxide titanium adj oxide titanium adj dioxide alumina aluminum adj oxide "Si.sub.3.N.sub.4" "Si.sub.3 N.sub.4" "Si0.sub.2" "Si O.sub.2" "Ti0.sub.2" "Ti O.sub.2" "Al.sub.20.sub.3" "Al.sub.2 O.sub.3")) and (257/\$ 438/\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 22:55
-	107		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 22:56
-	23		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 22:56
-	1236	barium adj strontium adj titanate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 23:58
_	478	(barium adj strontium adj titanate) and capacitor and (361/\$ 257/\$ 438/\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/17